

PS2506-1, PS2506L-1

R08DS0197EJ0100 Rev.1.00 Dec 25, 2020

HIGH ISOLATION VOLTAGE AC INPUT, DARLINGTON TRANSISTOR TYPE

DESCRIPTION

The PS2506-1 and PS2506L-1 are optically coupled isolator containing a GaAs light emitting diode and an NPN silicon darlington connected phototransistor.

The PS2506-1 is in a plastic DIP (Dual In-line Package) and the PS2506L-1 is lead bending type (Gull-wing) for surface mount.

FEATURES

- · AC input response
- High isolation voltage (BV = 5 000 Vr.m.s.)
- High current transfer ratio (CTR = 2 000 % TYP.)
- High-speed switching (t_r , $t_f = 100 \mu s$ TYP.)
- Ordering number of taping product: PS2506L-1-F3 : 2 000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL1577, Double protection

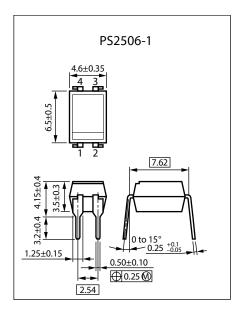
PIN CONNECTION (Top View) 1. Anode, Cathode 2. Cathode, Anode 3. Emitter 4. Collector

APPLICATIONS

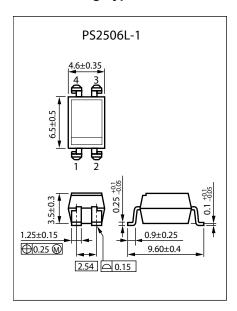
- · Power supply
- Telephone/FAX
- FA/OA equipment
- Programmable logic controller

PACKAGE DIMENSIONS (UNIT: mm)

DIP Type



Lead Bending Type For Surface Mount

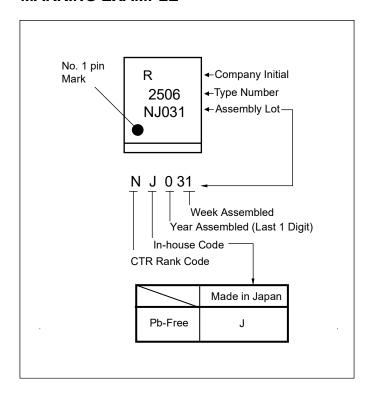


Weight (4-pin DIP) : 0.26 g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	PS2506-1, PS2506L-1
Air Distance (MIN.)	7 mm
Creepage Distance (MIN.)	7 mm
Isolation Distance (MIN.)	0.4 mm

MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number *1
PS2506-1	PS2506-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2506-1
PS2506L-1	PS2506L-1-A			 	PS2506L-1
PS2506L-1-F3	PS2506L-1-F3-A		Embossed Tape 2 000 pcs/reel		PS2506L-1

Notes: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	l _F	±80	mA	
	Power Dissipation Derating	⊿P _D /°C	1.5	mW/°C	
	Power Dissipation	PD	150	mW	
	Peak Forward Current*1	I _{FP}	±1	Α	
Transistor	Collector to Emitter Voltage	Vceo	40	V	
	Emitter to Collector Voltage	V _{ECO}	6	V	
	Collector Current	Ic	200	mA	
	Power Dissipation Derating	⊿Pc/°C	2.0	mW/°C	
	Power Dissipation	Pc	200	mW	
Isolation Voltage*2		BV	5 000	Vr.m.s.	
Operating Ambient Temperature		TA	-55 to +100	°C	
Storage Temperature		T _{stg}	-55 to +150	°C	

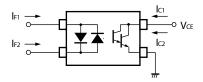
Note: *1. PW = 100 μ s, Duty Cycle = 1 %

^{*2.} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output. Pins 1-2 shorted together, 3-4 shorted together.

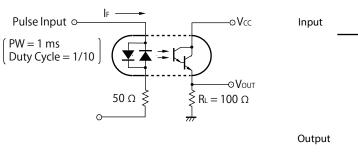
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

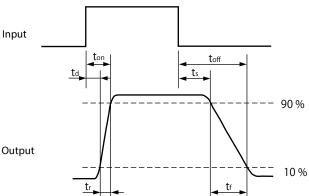
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = ±10 mA		1.17	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		100		pF
Transistor	Collector to Emitter Dark Current	Iceo	Vce = 40 V, IF = 0 mA			400	nA
Coupled	Current Transfer Ratio (Ic/IF)	CTR	IF = ±1 mA, VcE = 2 V	200	2 000		%
	CTR Ratio*1	CTR1/	I _F = 1 mA, V _{CE} = 2 V	0.3	1.0	3.0	
		CTR2					
	Collector Saturation Voltage	VCE (sat)	IF = ±1 mA, Ic = 2 mA			1.0	V
	Isolation Resistance	R _{I-0}	V _{I-O} = 1.0 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time*2	tr	Vcc = 10 V, Ic = 2 mA, RL = 100 Ω		100		μs
	Fall Time*2	tf			100		

Note: *1. CTR1 = I_{C1}/I_{F1} , CTR2 = I_{C2}/I_{F2}

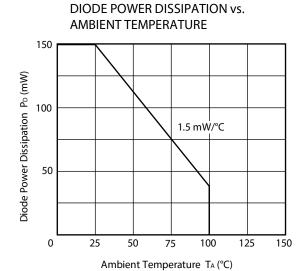


*2. Test Circuit for Switching Time

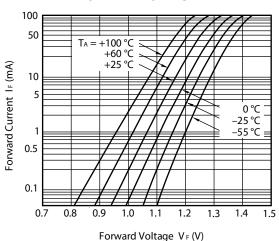




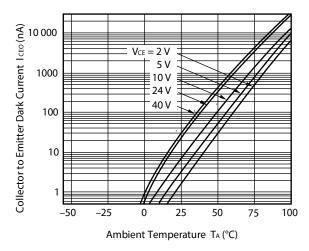
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)



FORWARD CURRENT vs. **FORWARD VOLTAGE**

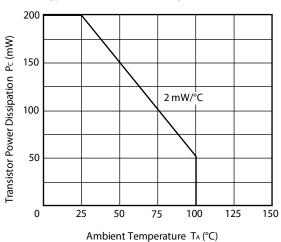


COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

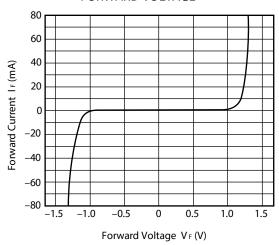


Remark The graphs indicate nominal characteristics.

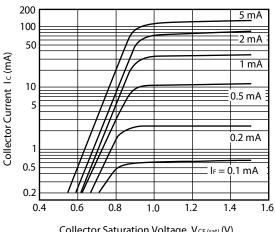




FORWARD CURRENT vs. FORWARD VOLTAGE

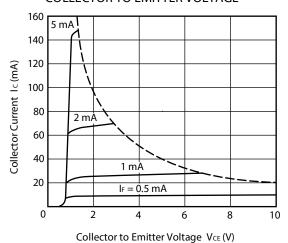


COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

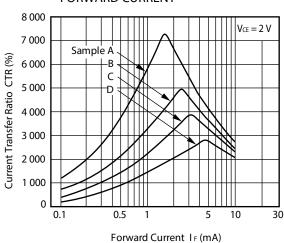


Collector Saturation Voltage VCE (sat) (V)

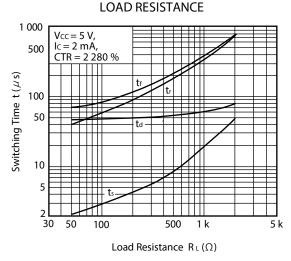
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



CURRENT TRANSFER RATIO vs. FORWARD CURRENT

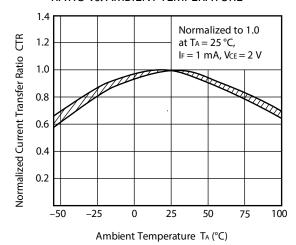


SWITCHING TIME vs.

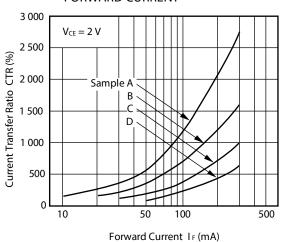


Remark The graphs indicate nominal characteristics.

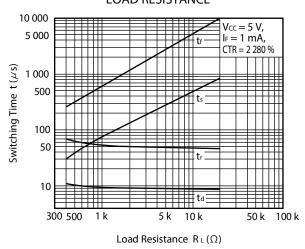
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



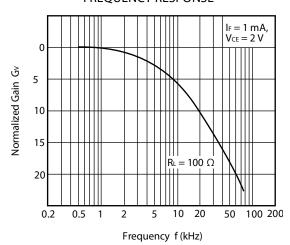
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



SWITCHING TIME vs. LOAD RESISTANCE



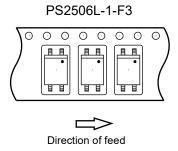
FREQUENCY RESPONSE



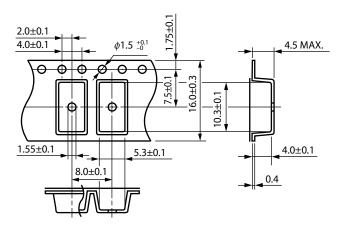
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

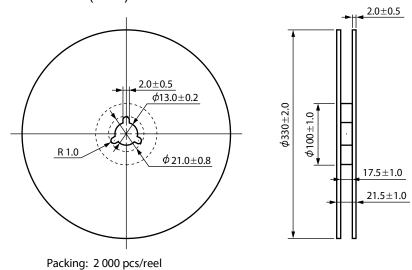
Taping Direction



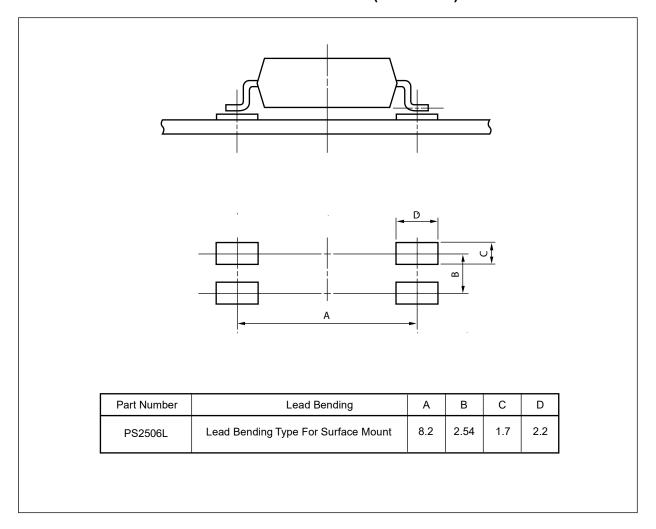
Outline and Dimensions (Tape)



Outline and Dimensions (Reel)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature 260 °C or below (package surface temperature)
 - Time of peak reflow temperature
 - Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

10 seconds or less

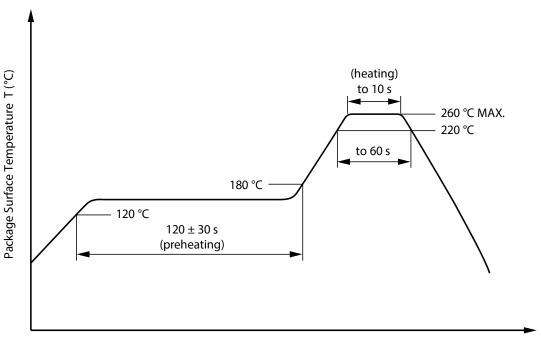
60 seconds or less

 $120 \pm 30 \text{ s}$ Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

 Preheating conditions 120 °C or below (package surface temperature)

One (Allowed to be dipped in solder including plastic mold portion.) Number of times • Flux Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

 Peak Temperature (lead part temperature) 350 °C or below · Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100 °C

(4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.

- 2. Cautions regarding noise
 - Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.
- 3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

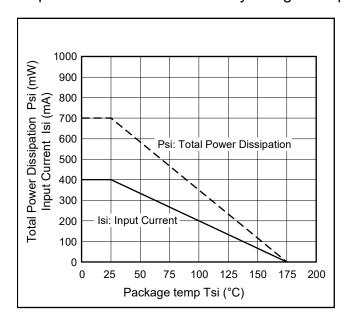
USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.
- 3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- 4. Do not use fixing agents or coatings containing halogen-based substances.

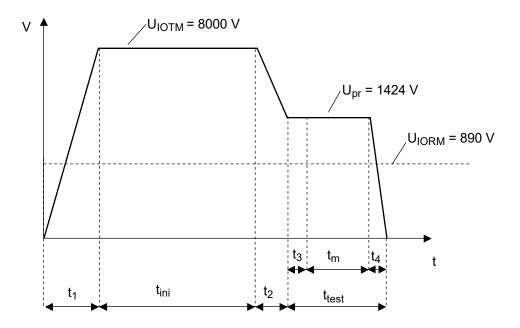
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$	UIORM Upr	890 1 424	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices) U_{pr} = 1.875 × U_{IORM} , P_d < 5 pC	U _{pr}	1 669	V_{peak}
Highest permissible overvoltage	U _{ІОТМ}	8 000	V _{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	СТІ	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value V _{IO} = 500 V dc at T _A = 25°C V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	175 400 700	°C mA mW
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature

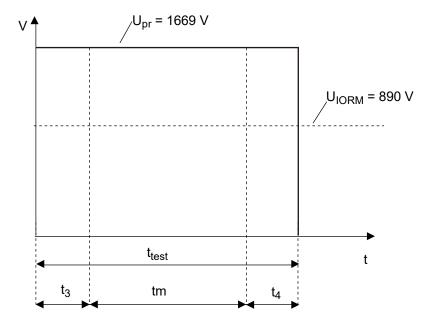


Method a) Destructive Test, Type and Sample Test



 t_1,t_2 = 1 to 10 sec t_3,t_4 = 1 sec $t_{m(PARTIAL\ DISCHARGE)}$ = 10 sec t_{test} = 12 sec t_{ini} = 60 sec

Method b) Non-destructive Test, 100 % Production Test



 t_3, t_4 = 0.1 sec $t_{m(PARTIAL\ DISCHARGE)}$ = 1.0 sec t_{test} = 1.2 sec

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or i any way allow it to enter the mouth.

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Renesas Electronics Corporation TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan Renesas Electronics America Inc.

1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A. Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited

9251 Yonge Street, St Tel: +1-905-237-2004 reet, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited

rand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Unit 1601-1611, 16/F., Tower 2, Grand Cent Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700

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